

Precision, Micropower LDO Voltage References in TSOT

ADR121/ADR125/ADR127

FEATURES

Initial accuracy A grade: ±0.24% B grade: ±0.12%

Maximum temperature coefficient

A grade: 25 ppm/°C B grade: 9 ppm/°C

Low dropout: 300 mV for ADR121/ADR125

High output current: +5 mA/-2 mA Low typical operating current: 85 μ A Input range: 2.7 V to 18 V for ADR127 Temperature range: -40° C to $+125^{\circ}$ C

Tiny TSOT (UJ-6) package

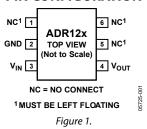
APPLICATIONS

Battery-powered instrumentation Portable medical equipment Data acquisition systems Automotive

GENERAL DESCRIPTION

The ADR121/ADR125/ADR127 are a family of micropower, high precision, series mode, band gap references with sink and source capability. The parts feature high accuracy and low power consumption in a tiny package. The ADR12x design includes a patented temperature-drift curvature correction technique that minimizes the nonlinearities in the output voltage vs. temperature characteristics.

PIN CONFIGURATION



The ADR12x is a low dropout voltage reference, requiring only 300 mV for the ADR121/ADR125 and 1.45 V for the ADR127 above the nominal output voltage on the input to provide a stable output voltage. This low dropout performance, coupled with the low 85 μA operating current, makes the ADR12x ideal for battery-powered applications.

Available in an extended industrial temperature range of -40° C to $+125^{\circ}$ C, the ADR121/ADR125/ADR127 are housed in the tiny TSOT (UJ-6) package.

TABLE OF CONTENTS

Features
Applications1
Pin Configuration1
General Description1
Revision History2
Specifications
ADR121 Electrical Characteristics
ADR125 Electrical Characteristics4
ADR127 Electrical Characteristics5
Absolute Maximum Ratings 6
Thermal Resistance
ESD Caution6
Typical Performance Characteristics
REVISION HISTORY
1/08—Rev. A to Rev. B
Changes to Table 1
Changes to Table 2
Changes to Table 35
Changes to Figure 52
Changes to Ordering Guide
5/07—Rev. 0 to Rev. A
Changes to Table 1
Changes to Table 24
Changes to Table 35
Added Thermal Hysteresis Faustion 7

6/06—Revision 0: Initial Version

erminologyl	1:
heory of Operation1	į (
Power Dissipation Considerations	l (
Input Capacitor	l (
Output Capacitor	l (
Applications Information1	L?
Basic Voltage Reference Connection	Ľ
Stacking Reference ICs for Arbitrary Outputs	Ľ
Negative Precision Reference Without Precision Resistors 1	Ľ
General-Purpose Current Source	Ľ
Outline Dimensions	18
Ordering Guide	18

SPECIFICATIONS

ADR121 ELECTRICAL CHARACTERISTICS

 $T_{\rm A}$ = 25°C, $V_{\rm IN}$ = 2.8 V to 18 V, $I_{\rm OUT}$ = 0 mA, unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions/Comments	Min	Тур	Max	Unit
OUTPUT VOLTAGE	V _{OUT}					
B Grade			2.497	2.5	2.503	V
A Grade			2.494	2.5	2.506	V
INITIAL ACCURACY ERROR	Voerr					
B Grade			-0.12		+0.12	%
A Grade			-0.24		+0.24	%
TEMPERATURE COEFFICIENT	TCV _{OUT}	-40°C < T _A < +125°C				
B Grade				3	9	ppm/°C
A Grade				15	25	ppm/°C
DROPOUT (V _{OUT} – V _{IN})	V _{DO}	I _{OUT} = 0 mA	300			mV
LOAD REGULATION		-40°C < T _A < +125°C; V _{IN} = 5.0 V, 0 mA < I _{OUT} < 5 mA		80	300	ppm/mA
		-40 °C < T_A < $+125$ °C; V_{IN} = 5.0 V, -2 mA < I_{OUT} < 0 mA		50	300	ppm/mA
LINE REGULATION		2.8 V to 18 V, I _{OUT} = 0 mA	-50	+3	+50	ppm/V
PSRR		f = 60 Hz		-90		dB
QUIESCENT CURRENT	IQ	-40°C < T _A < +125°C, no load				
		$V_{IN} = 18 V$		95	125	μΑ
		$V_{IN} = 2.8 V$		80	95	μΑ
SHORT-CIRCUIT CURRENT TO GROUND		V _{IN} = 2.8 V		18		mA
		$V_{IN} = 18 V$		40		mA
VOLTAGE NOISE		f = 10 kHz		500		nV/√Hz
		f = 0.1 Hz to 10 Hz		18		μV p-p
TURN-ON SETTLING TIME		To 0.1%, C _L = 0.2 μF		100		μs
LONG-TERM STABILITY		1000 hours @ 25°C		150		ppm/1000 hrs
OUTPUT VOLTAGE HYSTERESIS		See the Terminology section		300		ppm

ADR125 ELECTRICAL CHARACTERISTICS

 $T_{\rm A}$ = 25°C, $V_{\rm IN}$ = 5.3 V to 18 V, $I_{\rm OUT}$ = 0 mA, unless otherwise noted.

Table 2.

Parameter	Symbol	Conditions/Comments	Min	Тур	Max	Unit
OUTPUT VOLTAGE	V _{OUT}					
B Grade			4.994	5.0	5.006	V
A Grade			4.988	5.0	5.012	V
INITIAL ACCURACY ERROR	Voerr					
B Grade			-0.12		+0.12	%
A Grade			-0.24		+0.24	%
TEMPERATURE COEFFICIENT	TCV _{OUT}	-40°C < T _A < +125°C				
B Grade				3	9	ppm/°C
A Grade				15	25	ppm/°C
DROPOUT (V _{OUT} – V _{IN})	V_{DO}	I _{ОUТ} = 5 mA	300			mV
LOAD REGULATION		-40 °C < T_A < $+125$ °C; V_{IN} = 6.0 V, 0 mA < I_{OUT} < 5 mA		35	200	ppm/mA
		-40 °C < T_A < $+125$ °C; V_{IN} = 6.0 V, -2 mA < I_{OUT} < 0 mA		35	200	ppm/mA
LINE REGULATION		5.3 V to 18 V, I _{OUT} = 0 mA			30	ppm/V
PSRR		f = 60 Hz		-90		dB
QUIESCENT CURRENT	IQ	−40°C < T _A < +125°C, no load				
		V _{IN} = 18 V		95	125	μΑ
		V _{IN} = 5.3 V		80	95	μΑ
SHORT-CIRCUIT CURRENT TO GROUND		V _{IN} = 5.3 V		25		mA
		V _{IN} = 18 V		40		mA
VOLTAGE NOISE		f = 10 kHz		900		nV/√Hz
		f = 0.1 Hz to 10 Hz		36		μV p-p
TURN-ON SETTLING TIME		To 0.1%, C _L = 0.2 μF		100		μs
LONG-TERM STABILITY		1000 hours @ 25°C		150		ppm/1000 hrs
OUTPUT VOLTAGE HYSTERESIS		See the Terminology section		300		ppm

ADR127 ELECTRICAL CHARACTERISTICS

 $T_{\rm A}$ = 25°C, $V_{\rm IN}$ = 2.7 V to 18 V, $I_{\rm OUT}$ = 0 mA, unless otherwise noted.

Table 3.

Parameter	Symbol	Conditions/Comments	Min	Тур	Max	Unit
OUTPUT VOLTAGE	V _{OUT}					
B Grade			1.2485	1.25	1.2515	V
A Grade			1.2470	1.25	1.2530	V
INITIAL ACCURACY ERROR	Voerr					
B Grade			-0.12		+0.12	%
A Grade			-0.24		+0.24	%
TEMPERATURE COEFFICIENT	TCV _{OUT}	-40°C < T _A < +125°C				
B Grade				3	9	ppm/°C
A Grade				15	25	ppm/°C
DROPOUT (V _{OUT} – V _{IN})	V _{DO}	I _{OUT} = 0 mA	1.45			V
LOAD REGULATION		-40°C < T _A < $+125$ °C; V _{IN} = 3.0 V, 0 mA < I _{OUT} < 5 mA		85	400	ppm/mA
		-40 °C < T_A < $+125$ °C; V_{IN} = 3.0 V, -2 mA < I_{OUT} < 0 mA		65	400	ppm/mA
LINE REGULATION		2.7 V to 18 V, I _{OUT} = 0 mA		30	90	ppm/V
PSRR		f = 60 Hz		-90		dB
QUIESCENT CURRENT	IQ	-40°C < T _A < +125°C, no load				
		$V_{IN} = 18 V$		95	125	μΑ
		$V_{IN} = 2.7 V$		80	95	μΑ
SHORT-CIRCUIT CURRENT TO GROUND		$V_{IN} = 2.7 \text{ V}$		15		mA
		$V_{IN} = 18 V$		30		mA
VOLTAGE NOISE		f = 10 kHz		300		nV/√Hz
		f = 0.1 Hz to 10 Hz		9		μV p-p
TURN-ON SETTLING TIME		To 0.1%, C _L = 0.2 μF		80		μs
LONG-TERM STABILITY		1000 hours @ 25°C		150		ppm/1000 hrs
OUTPUT VOLTAGE HYSTERESIS		See the Terminology section		300		ppm

ABSOLUTE MAXIMUM RATINGS

Table 4.

Parameter	Rating
V _{IN} to GND	20 V
Internal Power Dissipation	
TSOT (UJ-6)	40 mW
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−40°C to +125°C
Lead Temperature, Soldering	
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

 θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 5.

Package Type	θја	θις	Unit
6-Lead TSOT (UJ-6)	230	146	°C/W

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

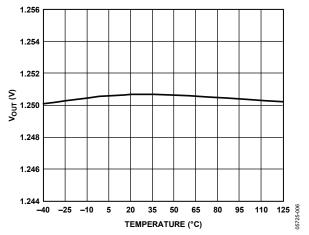


Figure 2. ADR127 V_{OUT} vs. Temperature

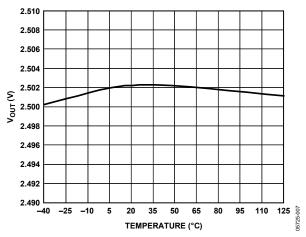


Figure 3. ADR121 V_{OUT} vs. Temperature

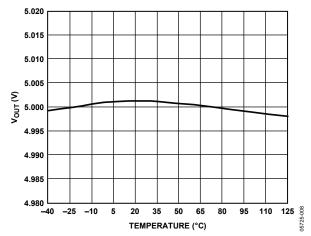


Figure 4. ADR125 Vout vs. Temperature

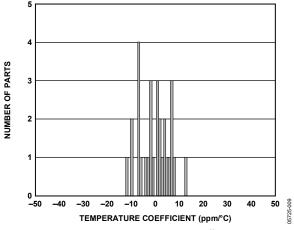


Figure 5. ADR127 Temperature Coefficient

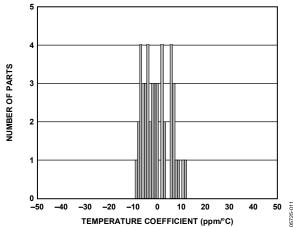


Figure 6. ADR121 Temperature Coefficient

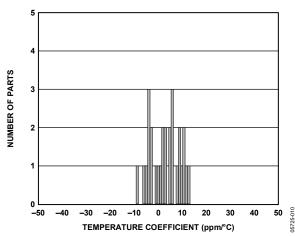


Figure 7. ADR125 Temperature Coefficient

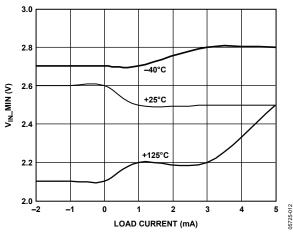


Figure 8. ADR127 Minimum Input Voltage vs. Load Current

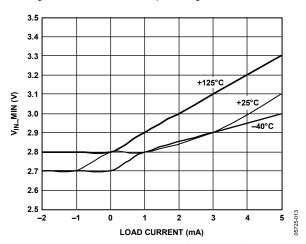


Figure 9. ADR121 Minimum Input Voltage vs. Load Current

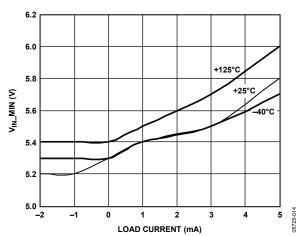


Figure 10. ADR125 Minimum Input Voltage vs. Load Current

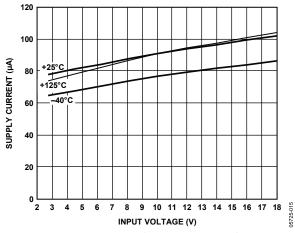


Figure 11. ADR127 Supply Current vs. Input Voltage

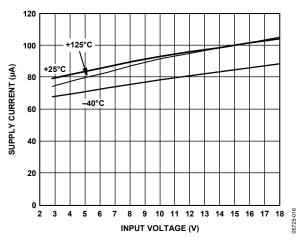


Figure 12. ADR121 Supply Current vs. Input Voltage

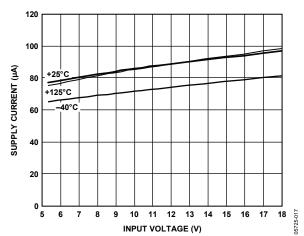


Figure 13. ADR125 Supply Current vs. Input Voltage

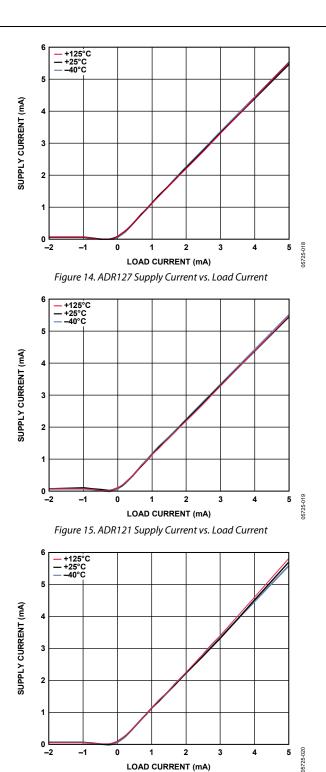


Figure 16. ADR125 Supply Current vs. Load Current

LINE REGULATION (ppm/V) V_{IN} = 2.7V TO 18V -30 **–40** -25 -10 35 50 65 110 TEMPERATURE (°C) Figure 17. ADR127 Line Regulation vs. Temperature LINE REGULATION (ppm/V) V_{IN} = 2.8V TO 18V 35 50 65 TEMPERATURE (°C) Figure 18. ADR121 Line Regulation vs. Temperature LINE REGULATION (ppm/V) V_{IN} = 5.3V TO 18V

50 65

125 e22-923

110

-40

-25 -10

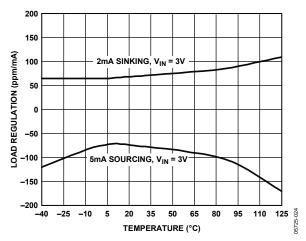


Figure 20. ADR127 Load Regulation vs. Temperature

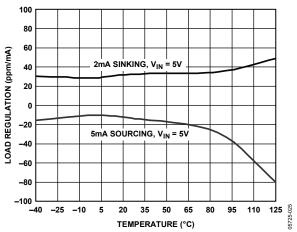


Figure 21. ADR121 Load Regulation vs. Temperature

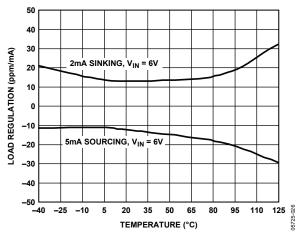


Figure 22. ADR125 Load Regulation vs. Temperature

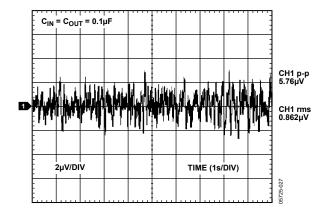


Figure 23. ADR127 0.1 Hz to 10 Hz Noise

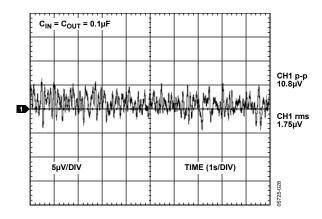


Figure 24. ADR121 0.1 Hz to 10 Hz Noise

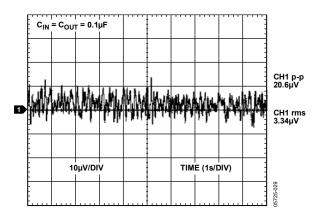


Figure 25. ADR125 0.1 Hz to 10 Hz Noise

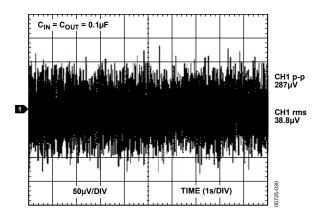


Figure 26. ADR127 10 Hz to 10 kHz Noise

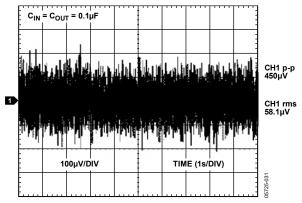


Figure 27. ADR121 10 Hz to 10 kHz Noise

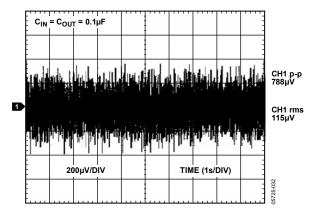


Figure 28. ADR125 10 Hz to 10 kHz Noise

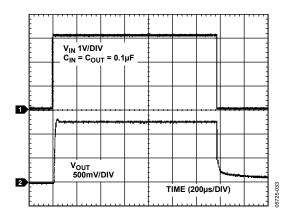


Figure 29. ADR127 Turn-On Response

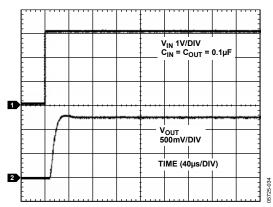


Figure 30. ADR127 Turn-On Response

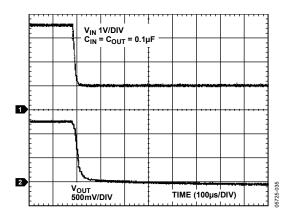


Figure 31. ADR127 Turn-Off Response

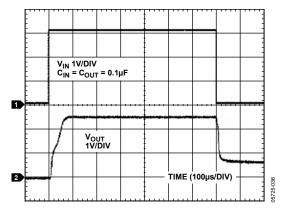


Figure 32. ADR121 Turn-On Response

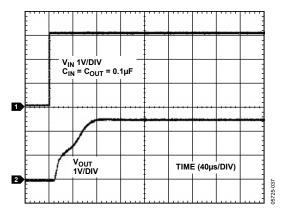


Figure 33. ADR121 Turn-On Response

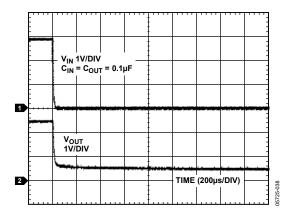


Figure 34. ADR121 Turn-Off Response

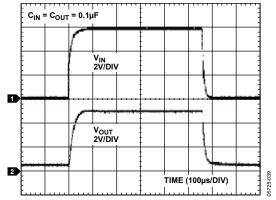


Figure 35. ADR125 Turn-On Response

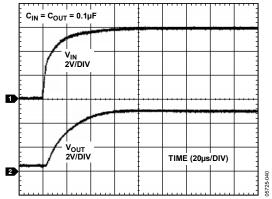


Figure 36. ADR125 Turn-On Response

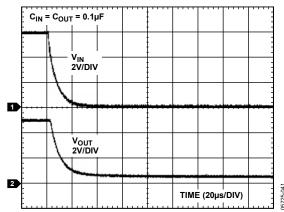


Figure 37. ADR125 Turn-Off Response

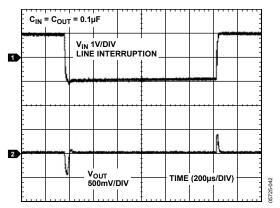


Figure 38. ADR127 Line Transient Response

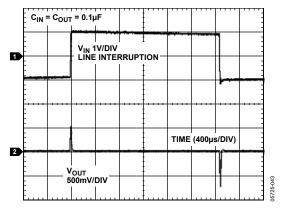


Figure 39. ADR121 Line Transient Response

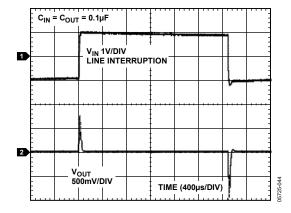


Figure 40. ADR125 Line Transient Response

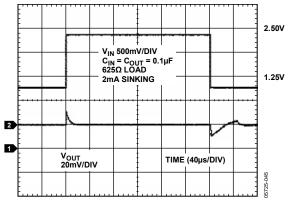


Figure 41. ADR127 Load Transient Response (Sinking)

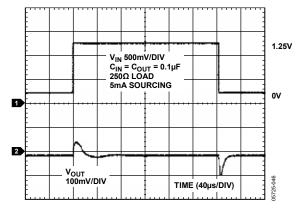


Figure 42. ADR127 Load Transient Response (Sourcing)

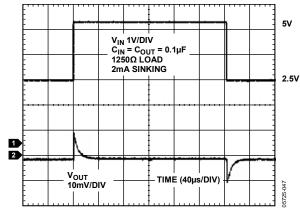


Figure 43. ADR121 Load Transient Response (Sinking)

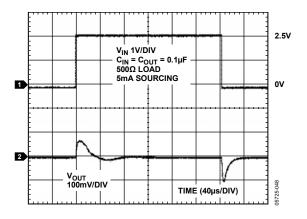


Figure 44. ADR121 Load Transient Response (Sourcing)

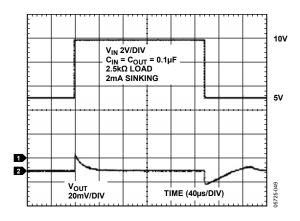


Figure 45. ADR125 Load Transient Response (Sinking)

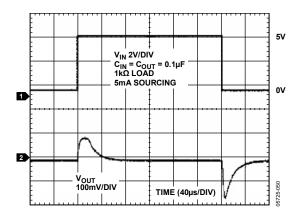


Figure 46. ADR125 Load Transient Response (Sourcing)

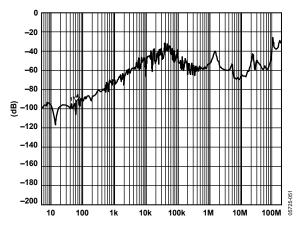


Figure 47. ADR121/ADR125/ADR127 PSRR

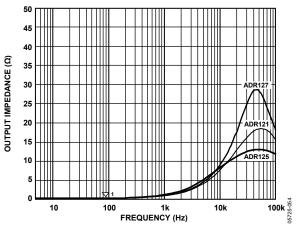


Figure 48. ADR121/ADR125/ADR127 Output Impedance vs. Frequency

TERMINOLOGY

Temperature Coefficient

The change in output voltage with respect to operating temperature change normalized by the output voltage at 25°C. This parameter is expressed in ppm/°C and can be determined as follows:

$$TCV_{OUT}[ppm/^{\circ}C] = \frac{V_{OUT}(T_2) - V_{OUT}(T_1)}{V_{OUT}(25^{\circ}C) \times (T_2 - T_1)} \times 10^6$$
 (1)

where.

 $V_{OUT}(25^{\circ}\text{C}) = V_{OUT} \text{ at } 25^{\circ}\text{C}.$

 $V_{OUT}(T_1) = V_{OUT}$ at Temperature 1.

 $V_{OUT}(T_2) = V_{OUT}$ at Temperature 2.

Line Regulation

The change in the output voltage due to a specified change in input voltage. This parameter accounts for the effects of self-heating. Line regulation is expressed in percent per volt, parts-per-million per volt, or microvolts per voltage change in input voltage.

Load Regulation

The change in output voltage due to a specified change in load current. This parameter accounts for the effects of self-heating. Load regulation is expressed in microvolts per milliampere, parts-per-million per milliampere, or ohms of dc output resistance.

Long-Term Stability

Typical shift of output voltage at 25°C on a sample of parts subjected to a test of 1000 hours at 25°C.

$$\Delta V_{OUT} V_{OUT}(t_0) - V_{OUT}(t_I)$$

$$\Delta V_{OUT}[ppm] = \frac{V_{OUT}(t_0) - V_{OUT}(t_I)}{V_{OUT}(t_0)} \times 10^6$$
(2)

where:

 $V_{OUT}(t_0) = V_{OUT}$ at 25°C at Time 0.

 $V_{OUT}(t_1) = V_{OUT}$ at 25°C after 1000 hours operating at 25°C.

Thermal Hysteresis

The change in output voltage after the device is cycled through temperatures from $+25^{\circ}$ C to -40° C to $+125^{\circ}$ C and back to $+25^{\circ}$ C. This is a typical value from a sample of parts put through such a cycle.

$$V_{OUT_HYS} = V_{OUT} (25^{\circ}C) - V_{OUT_TC}$$

$$V_{OUT_HYS} [ppm] = \frac{V_{OUT} (25^{\circ}C) - V_{OUT_TC}}{V_{OUT} (25^{\circ}C)} \times 10^{6}$$
(3)

where:

 $V_{OUT}(25^{\circ}\text{C}) = V_{OUT} \text{ at } 25^{\circ}\text{C}.$

 V_{OUT_TC} = V_{OUT} at 25°C after temperature cycle at +25°C to -40°C to +125°C and back to +25°C.

THEORY OF OPERATION

The ADR12x band gap references are the high performance solution for low supply voltage and low power applications. The uniqueness of these products lies in their architecture.

POWER DISSIPATION CONSIDERATIONS

The ADR12x family is capable of delivering load currents up to 5 mA with an input range from 3.0 V to 18 V. When this device is used in applications with large input voltages, care must be taken to avoid exceeding the specified maximum power dissipation or junction temperature because this could result in premature device failure.

Use the following formula to calculate a device's maximum junction temperature or dissipation:

$$P_D = \frac{T_{J-} T_A}{\theta_{IA}} \tag{4}$$

where:

 T_I is the junction temperature.

 T_A is the ambient temperature.

 P_D is the device power dissipation.

 θ_{JA} is the device package thermal resistance.

INPUT CAPACITOR

Input capacitors are not required on the ADR12x. There is no limit for the value of the capacitor used on the input, but a 1 μF to 10 μF capacitor on the input may improve transient response in applications where there is a sudden supply change. An additional 0.1 μF capacitor in parallel also helps reduce noise from the supply.

OUTPUT CAPACITOR

The ADR12x requires a small 0.1 μ F capacitor for stability. Additional 0.1 μ F to 10 μ F capacitance in parallel can improve load transient response. This acts as a source of stored energy for a sudden increase in load current. The only parameter affected with the additional capacitance is turn-on time.

APPLICATIONS INFORMATION

BASIC VOLTAGE REFERENCE CONNECTION

The circuit in Figure 49 illustrates the basic configuration for the ADR12x family voltage reference.

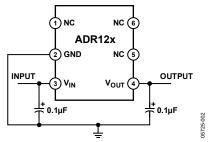


Figure 49. Basic Configuration for the ADR12x Family

STACKING REFERENCE ICs FOR ARBITRARY OUTPUTS

Some applications may require two reference voltage sources that are a combined sum of the standard outputs. Figure 50 shows how this stacked output reference can be implemented.

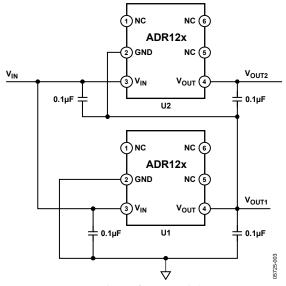


Figure 50. Stacking References with the ADR12x

Two reference ICs are used and fed from an unregulated input, $V_{\rm IN}$. The outputs of the individual ICs are connected in series, which provides two output voltages, $V_{\rm OUT1}$ and $V_{\rm OUT2}$. $V_{\rm OUT1}$ is the terminal voltage of U1, whereas $V_{\rm OUT2}$ is the sum of this voltage and the terminal of U2. U1 and U2 are chosen for the two voltages that supply the required outputs (see Table 6). For example, if U1 and U2 are ADR127s and $V_{\rm IN} \geq 3.95$ V, $V_{\rm OUT1}$ is 1.25 V and $V_{\rm OUT2}$ is 2.5 V.

Table 6. Required Outputs

U1/U2	V _{OUT2}	V _{OUT1}
ADR127/ADR121	1.25 V	3.75 V
ADR127/ADR125	1.25 V	6.25 V
ADR121/ADR125	2.5 V	7.5 V

NEGATIVE PRECISION REFERENCE WITHOUT PRECISION RESISTORS

A negative reference is easily generated by adding an op amp, for example, the AD8603, and is configured as shown in Figure 51. V_{OUT} is at virtual ground and, therefore, the negative reference can be taken directly from the output of the op amp. The op amp must be dual-supply, low offset, and rail-to-rail if the negative supply voltage is close to the reference output.

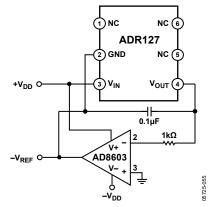


Figure 51. Negative Reference

GENERAL-PURPOSE CURRENT SOURCE

In low power applications, the need can arise for a precision current source that can operate on low supply voltages. The ADR12x can be configured as a precision current source (see Figure 52). The circuit configuration shown is a floating current source with a grounded load. The reference's output voltage is bootstrapped across R_{SET} , which sets the output current into the load. With this configuration, circuit precision is maintained for load currents ranging from the reference's supply current, typically 85 μA , to approximately 5 mA.

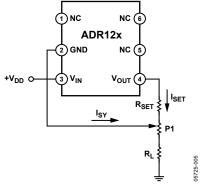
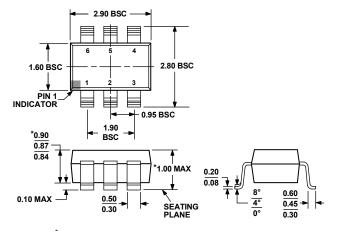


Figure 52. ADR12x Trim Configuration

OUTLINE DIMENSIONS



*COMPLIANT TO JEDEC STANDARDS MO-193-AA WITH THE EXCEPTION OF PACKAGE HEIGHT AND THICKNESS.

Figure 53. 6-Lead Thin Small Outline Transistor Package [TSOT] (UJ-6) Dimensions shown in millimeters

ORDERING GUIDE

	Output Voltage	l _	tial ıracy	Temperature Coefficient	Temperature	Package	Package	Ordering	
Model	(V ou⊤)	mV	±%	(ppm/°C)	Range	Description	Option	Quantity	Branding
ADR121AUJZ-REEL7 ¹	2.5	2.5	0.24	25	-40°C to +125°C	6-Lead TSOT	UJ-6	3,000	RON
ADR121AUJZ-R2 ¹	2.5	2.5	0.24	25	−40°C to +125°C	6-Lead TSOT	UJ-6	250	RON
ADR121BUJZ-REEL7 ¹	2.5	2.5	0.12	9	−40°C to +125°C	6-Lead TSOT	UJ-6	3,000	ROP
ADR125AUJZ-REEL71	5.0	5.0	0.24	25	-40°C to +125°C	6-Lead TSOT	UJ-6	3,000	R0Q
ADR125AUJZ-R21	5.0	5.0	0.24	25	-40°C to +125°C	6-Lead TSOT	UJ-6	250	R0Q
ADR125BUJZ-REEL7 ¹	5.0	5.0	0.12	9	-40°C to +125°C	6-Lead TSOT	UJ-6	3,000	ROR
ADR127AUJZ-REEL71	1.25	3	0.24	25	−40°C to +125°C	6-Lead TSOT	UJ-6	3,000	ROS
ADR127AUJZ-R21	1.25	3	0.24	25	−40°C to +125°C	6-Lead TSOT	UJ-6	250	ROS
ADR127BUJZ-REEL7 ¹	1.25	1.5	0.12	9	-40°C to +125°C	6-Lead TSOT	UJ-6	3.000	ROT

¹ Z = RoHS Compliant Part.

NOTES

ADR121	I/ADR1	25/ <i> </i>	\DR `	127

NOTES